

## CLAIMS

1. An optical device comprising:

a plurality of high index layers;

a plurality of low index layers;

wherein said optical device is formed by creating alternating layers of said plurality of high index layers and said plurality of low index layers, such that electricity and heat is conducted through said optical device.

2. The optical device of claim 1 further comprising that the index difference between said a plurality of high index layers and said plurality of low index layers is greater than 0.3.

3. The optical device of claim 2, wherein the said plurality of high index layers are Indium Tin Oxides.

4. The optical device of claim 2, wherein said plurality of high index layers are doped diamonds.

5. The optical device of claim 2, wherein said plurality of low index layers are doped silicon.

6. The optical device of claim 2, wherein said plurality of low index layers possess wide band gaps.

7. The optical device of claim 6, wherein said wide band gaps ensure that the loss in said optical device will be due to scattering off carriers.

1 8. The optical device of claim 6, wherein said low index layers exhibit low  
2 absorption losses.

1 9. The optical device of claim 1, wherein said alternating layers form tunneling  
2 junctions between said plurality of high index layer and said low index layers.

1 10. The optical device of claim 2, wherein said plurality of high index layers  
2 result in large reflectivity over a wide frequency bandwidth.

1 11. The optical device of claim 1, wherein said optical device is fabricated by  
2 sputtering said alternating layers.

1 12. The optical device of claim 1, wherein said optical device is fabricated by  
2 bonding.

1 13. The optical device of claim 1, wherein said optical device is fabricated by  
2 utilizing smart cut technique.

1 14. The optical device of claim 1, wherein said optical device is fabricated by  
2 utilizing polishing technique.

1 15. A method of forming an optical device, comprising  
2 providing a plurality of high index layers;  
3 providing a plurality of low index layers;  
4 wherein said optical device is formed by creating alternating layers of said  
5 plurality of high index layers and said plurality of low index layers, such that  
6 electricity and heat is conducted through said optical device.

1 16. The method of claim 15 further comprising that the index difference between  
2 said a plurality of high index layers and said plurality of low index layers is greater than  
3 0.3.

1 17. The method of claim 16, wherein the said plurality of high index layers are  
2 Indium Tin Oxides.

1 18. The method of claim 16, wherein said plurality of high index layers are doped  
2 diamonds.

1 19. The method of claim 16, wherein said plurality of low index layers are doped  
2 silicon.

1 20. The method of claim 16, wherein said plurality of low index layers possess  
2 wide band gaps.

1 21. The method of claim 20, wherein said wide band gaps ensure that the loss in  
2 said optical device will be due to scattering off carriers.

1 22. The method of claim 20, wherein said low index layers exhibit low  
2 absorption losses.

1 23. The method of claim 15, wherein said alternating layers form tunneling  
2 junctions between said plurality of high index layer and said low index layers.

1 24. The method of claim 16, wherein said plurality of high index layers result in  
2 large reflectivity over a wide frequency bandwidth.

1 25. The method of claim 15, wherein said optical device is fabricated by  
2 sputtering said alternating layers.

1 26. The method of claim 15, wherein said optical device is fabricated by bonding.

1 27. The method of claim 15, wherein said optical device is fabricated by utilizing  
2 smart cut technique.

1 28. The method of claim 15, wherein said optical device is fabricated by utilizing  
2 polishing technique.

1 29. A Fabry-Perot device comprising:

2 a plurality of high index layers;

3 a plurality of low index layers;

4 a top mirror that includes alternating layers of said plurality of high index  
5 layers and said plurality of low index layers;

6 a cavity structure that includes a bulk of a selective material; and

7 a bottom mirror that includes alternating layers of said plurality of high  
8 index layers and said plurality of low index layers;

9 wherein said top mirror and bottom mirror allow electricity and heat to be  
10 conducted through said Fabry-Perot device.

1 30. A process for forming an optical device, comprising

2 providing a plurality of high index layers;

3 providing a plurality of low index layers;

4 wherein said optical device is formed by creating alternating layers of said  
5 plurality of high index layers and said plurality of low index layers, such that  
6 electricity and heat is conducted through said optical device.

1 31. The process of claim 30 further comprising that the index difference between  
2 said a plurality of high index layers and said plurality of low index layers is greater than  
3 0.3.

1 32. The process of claim 31, wherein the said plurality of high index layers are  
2 Indium Tin Oxides.

1 33. The process of claim 31, wherein said plurality of high index layers are doped  
2 diamonds.

1 34. The process of claim 31, wherein said plurality of low index layers are doped  
2 silicon.

1 35. The process of claim 31, wherein said plurality of low index layers possess  
2 wide band gaps.

1 36. The process of claim 35, wherein said wide band gaps ensure that the loss in  
2 said optical device will be due to scattering off carriers.

1 37. The process of claim 35, wherein said low index layers exhibit low  
2 absorption losses.

1 38. The process of claim 30, wherein said alternating layers form tunneling  
2 junctions between said plurality of high index layer and said low index layers.

1           39. The process of claim 31, wherein said plurality of high index layers result in  
2 large reflectivity over a wide frequency bandwidth.

1           40. The process of claim 30, wherein said optical device is fabricated by  
2 sputtering said alternating layers.

1           41. The process of claim 30, wherein said optical device is fabricated by bonding.

1           42. The process of claim 30, wherein said optical device is fabricated by utilizing  
2 smart cut technique.

1           43. The process of claim 30, wherein said optical device is fabricated by utilizing  
2 polishing technique.

1           44. A method of forming a Fabry-Perot device comprising:

2               providing a plurality of high index layers;

3               providing a plurality of low index layers;

4               forming a top mirror that includes alternating layers of said plurality of  
5 high index layers and said plurality of low index layers;

6               forming a cavity structure that includes a bulk of a selective material; and

7               forming a bottom mirror that includes alternating layers of said plurality of  
8 high index layers and said plurality of low index layers;

9               wherein said top mirror and bottom mirror allow electricity and heat to be  
10 conducted through said Fabry-Perot device